



SOURCING
SEMI

SESF16N1812PH
ESD Protection Diode

Features

- 1700Watts peak pulse power ($t_p = 8/20\mu s$)
- Tiny DFN1610 package
- Unidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection one power line to:
- IEC 61000-4-2 $\pm 30kV$ contact $\pm 30kV$ air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 45A (8/20 μs)



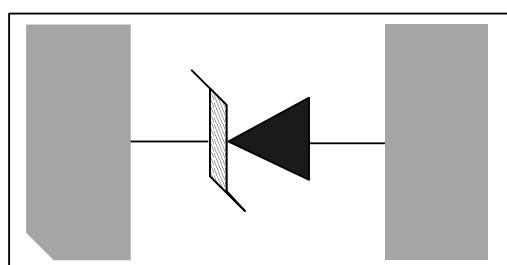
Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

Mechanical Data

- DFN1610 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Schematic & PIN Configuration



DFN1610

Absolute Maximum Rating

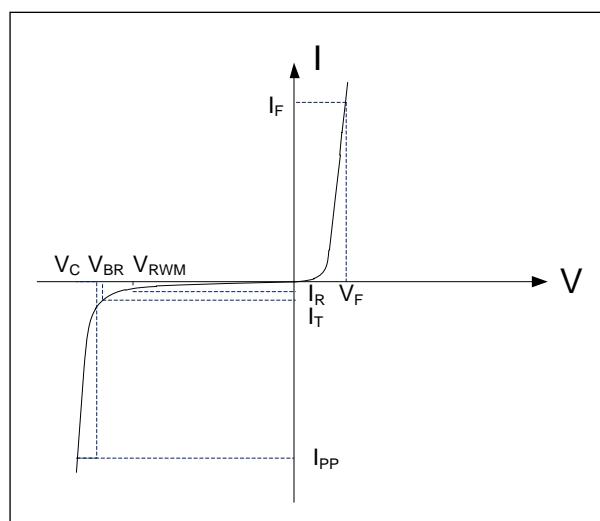
Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	1500	Watts
Peak Pulse Current ($t_p = 8/20\mu s$) (note1)	I_{PP}	45	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	30 30	kV
Lead Soldering Temperature	T_L	260(10seconds)	°C
Junction Temperature	T_J	-55 to + 125	°C
Storage Temperature	T_{stg}	-55 to + 125	°C

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				18.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	19.5			V
Reverse Leakage Current	I_R	$V_{RWM}=18.0V, T=25^\circ C$			1	μA
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$		45		A
Clamping Voltage	V_C	$I_{PP}=45A, t_p=8/20\mu s$		38		V
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$		300		pF

Electrical Parameters (TA = 25 °C unless otherwise noted)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current



Note: 8/20μs pulse waveform.

Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

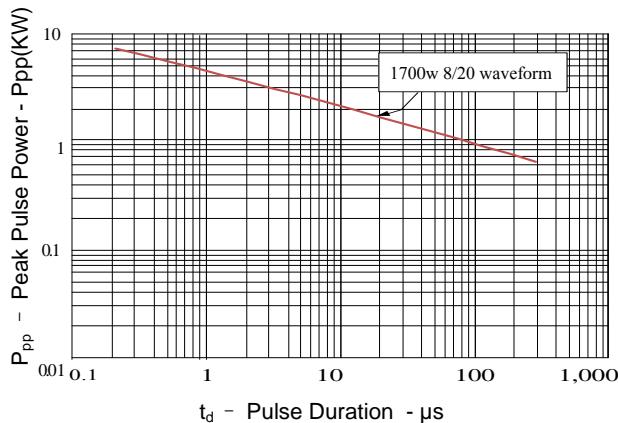


Figure 2: Power Derating Curve

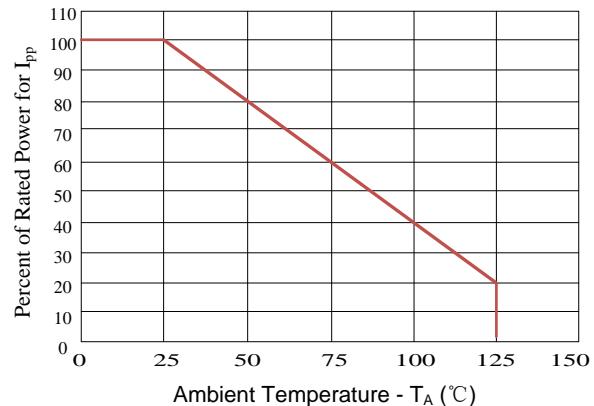


Figure 3: Pulse Waveform

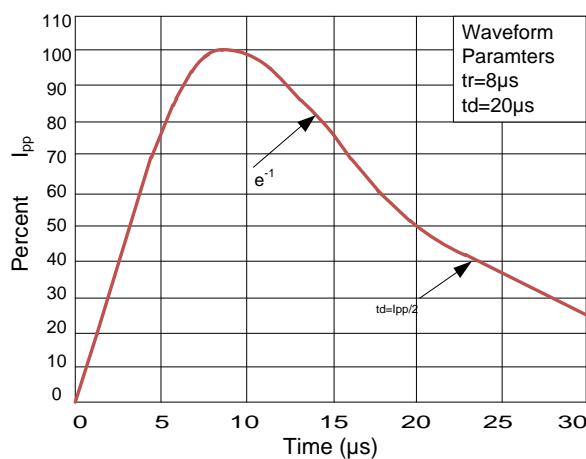
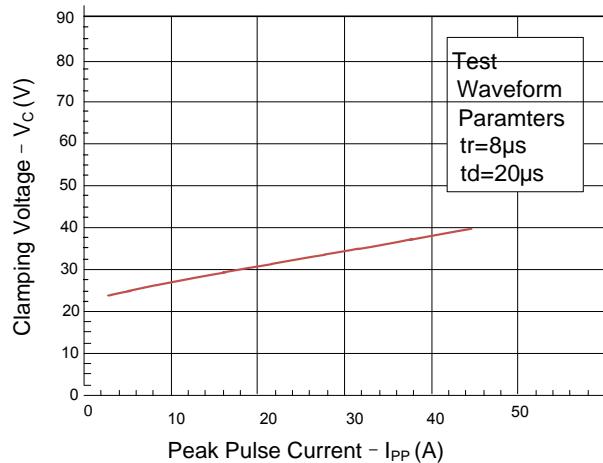
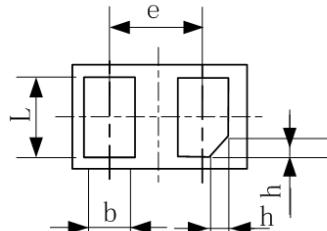
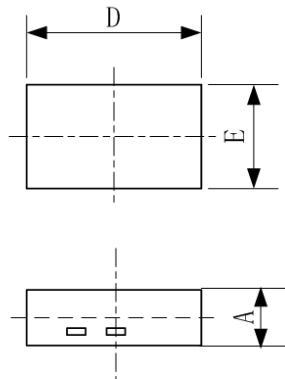


Figure 4: Clamping Voltage vs.Ipp



Outline Drawing – DFN1610



COMMON DIEMENSION (MM)			
PKG	DFN1610		
REF.	MIN.	NON.	MAX.
A	0.45	0.50	0.55
D	1.55	1.60	1.65
E	0.95	1.00	1.05
b	0.35	0.40	0.45
L	0.75	0.80	0.85
e	1.10BSC		
h	0.15	0.20	0.25

Marking



Ordering information

Order code	Package	Base qty	Delivery mode
SESF16N1812PH	DFN1610	10k	Tape and reel